

Low Phase Noise VCXO with multipliers (for 100-200MHz Fund Xtal)

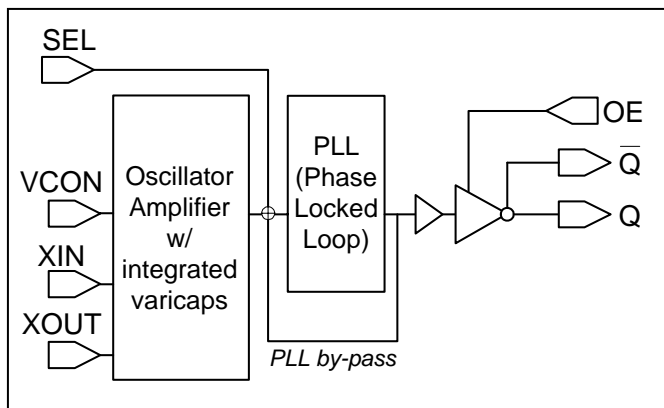
FEATURES

- 100MHz to 200MHz Fundamental Mode Crystal.
- Output range: 100 – 200MHz (no multiplication), 200 – 400MHz (2x multiplier), 400 – 800MHz (4x multiplier), or 800MHz – 1GHz (ABV2009 TSSOP only, 8x multiplier).
- High yield design supports up to 2pF stray capacitance at 200MHz.
- CMOS (Standard drive ABV2007 or Selectable Drive ABV2006), PECL (Enable low ABV2008 or Enable high ABV2005) or LVDS output (ABV2009).
- Integrated variable capacitors.
- Supports 3.3V-Power Supply.
- Available in 16-Pin (TSSOP or 3x3mm QFN)
Note: ABV2006 only available in 3x3mm.
Note: ABV2007 only available in TSSOP.

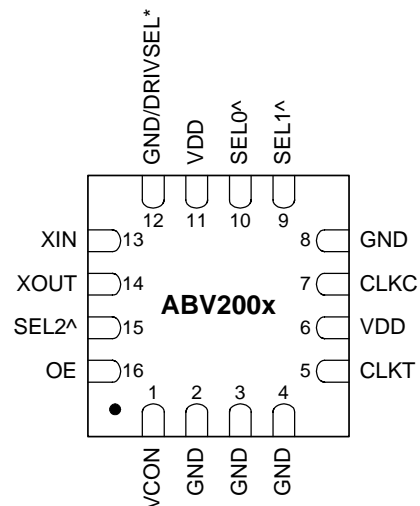
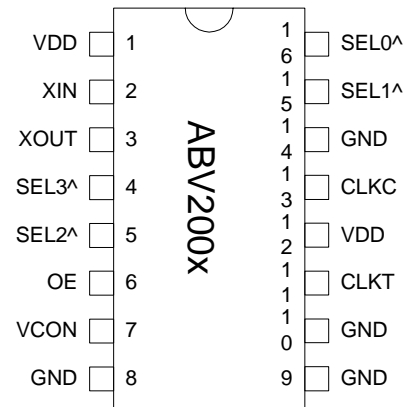
DESCRIPTION

The ABV2005/-06/-07/-08/-09 is a family of VCXO ICs specifically designed to pull high frequency fundamental crystals. Their design was optimized to tolerate higher limits of interelectrode capacitance and bonding capacitance to improve yield. They achieve very low current into the crystal resulting in better overall stability. Their internal varicaps allow an on chip frequency pulling, controlled by the VCON input.

BLOCK DIAGRAM



PIN CONFIGURATION (Top View)



- [^]: Internal pull-up
- *: ABV2006 pin 12 is output drive select (DRIVSEL)
(0 for High Drive CMOS, 1 for Standard Drive CMOS)

OUTPUT ENABLE LOGICAL LEVELS

Part #	OE	State
ABV2008	0 (Default)	Output enabled
	1	Tri-state
ABV2005 ABV2006 ABV2007 ABV2009	0	Tri-state
	1 (Default)	Output enabled

OE input: Logical states defined by PECL levels for ABV2008
Logical states defined by CMOS levels for ABV2005/-06/-07/-09

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PIN DESCRIPTIONS

Name	TSSOP* Pin number	3x3mm QFN* Pin number	Type	Description
XIN	2	13	I	Crystal in connector.
XOUT	3	14	I	Crystal out connector.
OE	6	16	I	Output enable pin.
VCON	7	1	I	Frequency control input (0.3V to 3.0V)
GND	8,9, 10, 14	2,3,4,8,12	P	Ground (except pin 12 on ABV2006: DRIVSEL see below).
DRIVSEL**	-	12	I	ABV2006 only: Drive Select Input. This pin has an internal pull-up that will default DRIVSEL to '1' when not connect to GND. CMOS output of ABV2006 will be high drive CMOS when DRIVSEL is set to '0', and will be standard CMOS otherwise.
CLKT	11	5	O	True output PECL (ABV2008) or LVDS (ABV2009) (N/C for ABV2007)
CLKC	13	7	O	Complementary output PECL (ABV2008) or LVDS (ABV2009) (CMOS out for ABV2007).
SEL0	16	10	I	Multiplier selector pins. These pins have an internal pull-up that will default SEL to '1' when not connected to GND.
SEL1	15	9	I	
SEL2	5	15	I	
SEL3	4	Not available	I	
VDD	1, 12	6,11	P	+3.3V power supply.

* Note: ABV2006 only available in 3x3mm QFN, ABV2007 only available in TSSOP.

** Note: DRIVSEL on pin 12 on ABV2006 only.

FREQUENCY SELECTION TABLE

SEL3*	SEL2	SEL1	SEL0	Selected Multiplier
0*	0	1	1	Fin x 8 (ABV2009 in TSSOP only)
1*	0	1	1	Fin x 4
1*	1	1	0	Fin x 2
1*	1	1	1	No multiplication

Note *: SEL3 is not available (always "1") in 3x3mm package

All pins have internal pull-ups (default value is 1). Connect to GND to set to 0.

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ELECTRICAL SPECIFICATIONS

1. Absolute Maximum Ratings

PARAMETERS	SYMBOL	MIN.	MAX.	UNITS
Supply Voltage	V _{DD}		4.6	V
Input Voltage, dc	V _I	-0.5	V _{DD} +0.5	V
Output Voltage, dc	V _O	-0.5	V _{DD} +0.5	V
Storage Temperature	T _S	-65	150	°C
Ambient Operating Temperature*	T _A	-40	85	°C
Junction Temperature	T _J		125	°C
Lead Temperature (soldering, 10s)			260	°C
ESD Protection, Human Body Model			2	kV

Exposure of the device under conditions beyond the limits specified by Maximum Ratings for extended periods may cause permanent damage to the device and affect product reliability. These conditions represent a stress rating only, and functional operations of the device at these or any other conditions above the operational limits noted in this specification is not implied.

* Note: Operating Temperature is guaranteed by design for all parts (COMMERCIAL and INDUSTRIAL), but tested for COMMERCIAL grade only.

2. Crystal Specifications

PARAMETERS	SYMBOL	CONDITIONS	MIN.	MAX.	UNITS
Crystal Resonator Frequency	F _{XIN}	Parallel Fundamental Mode	100	200	MHz
Crystal Loading Rating	C _{L (xtal)}	Die at VCON = 1.65V		4	pF
Interelectrode Capacitance	C ₀			3.5	pF
Crystal Pullability	C ₀ /C _{1 (xtal)}	AT cut		250	-
Recommended ESR	R _E	AT cut		30	Ω

3. Voltage Controlled Crystal Oscillator

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
VCXO Stabilization Time *	T _{VCXOSTB}	From power valid			10	ms
VCXO Tuning Range		F _{XIN} = 100 – 200MHz; XTAL C ₀ /C ₁ < 250 0V ≤ VCON ≤ 3.3V		200*		ppm
CLK output pullability		VCON=1.65V, ±1.65V	±100*			ppm
On-chip Varicaps control range		VCON = 0 to 3.3V		4 – 18*		pF
Linearity					10*	%
VCXO Tuning Characteristic				65		ppm/V
VCON input impedance				60		kΩ
VCON modulation BW		0V ≤ VCON ≤ 3.3V, -3dB	25			kHz

Note: Parameters denoted with an asterisk (*) represent nominal characterization data and are not production tested to any specific limits.

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4. General Electrical Specifications

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Supply Current (Loaded Outputs)	I _{DD}	PECL/LVDS/CMOS			100/80/40	mA
Operating Voltage	V _{DD}		2.97		3.63	V
Output Clock Duty Cycle		@ 50% V _{DD} (CMOS)	45	50	55	%
		@ 1.25V (LVDS)	45	50	55	
		@ V _{DD} - 1.3V (PECL)	45	50	55	
Short Circuit Current				±50		mA

5. Jitter Specifications

PARAMETERS	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Period jitter RMS	At 155.52MHz, with capacitive decoupling between VDD and GND. Over 10,000 cycles		2.5		ps
Period jitter peak-to-peak			18.5	20	
Accumulated jitter RMS	At 155.52MHz, with capacitive decoupling between VDD and GND. Over 1,000,000 cycles.		2.5		ps
Accumulated jitter peak-to-peak			24	27	
Random Jitter	"RJ" measured on Wavecrest SIA 3000		2.5		ps
Integrated jitter RMS at 155MHz	Integrated 12 kHz to 20 MHz		0.3	0.4	ps
Period jitter RMS	At 622.08MHz, with capacitive decoupling between VDD and GND. Over 10,000 cycles		11		ps
Period jitter peak-to-peak			45	49	
Accumulated jitter RMS	At 622.08MHz, with capacitive decoupling between VDD and GND. Over 1,000,000 cycles.		11		ps
Accumulated jitter peak-to-peak			24	27	
Random Jitter	"RJ" measured on Wavecrest SIA 3000		3		ps
Integrated jitter RMS at 622MHz	Integrated 12 kHz to 20 MHz		1.6	1.8	ps

Measured on Wavecrest SIA 3000

6. Phase Noise Specifications

PARAMETERS	FREQUENCY	@10Hz	@100Hz	@1kHz	@10kHz	@100kHz	UNITS
Phase Noise relative to carrier	155.52MHz	-75	-95	-125	-140	-145	dBc/Hz
	622.08MHz	-75	-95	-110	-125	-120	

Note: Phase Noise measured at VCON = 0V

7. CMOS Electrical Specifications

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Output drive current (High Drive)	I _{OH}	V _{OH} = V _{DD} -0.4V, V _{DD} =3.3V	30			mA
	I _{OL}	V _{OL} = 0.4V, V _{DD} = 3.3V	30			mA
Output drive current (Standard Drive)	I _{OH}	V _{OH} = V _{DD} -0.4V, V _{DD} =3.3V	10			mA
	I _{OL}	V _{OL} = 0.4V, V _{DD} = 3.3V	10			mA
Output Clock Rise/Fall Time (Standard Drive)		0.3V ~ 3.0V with 15 pF load		2.4		ns
Output Clock Rise/Fall Time (High Drive)		0.3V ~ 3.0V with 15 pF load		1.2		

* Note: High Drive CMOS is available on ABV2006 through DRIVSEL selector input on pin 12.

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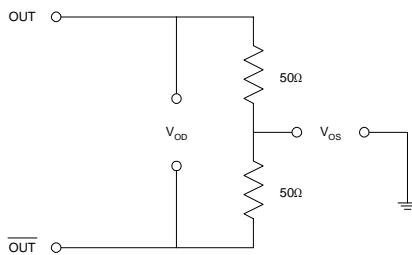
8. LVDS Electrical Characteristics

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Output Differential Voltage	V_{OD}	$R_L = 100 \Omega$ (see figure)	247	355	454	mV
V_{DD} Magnitude Change	ΔV_{OD}		-50		50	mV
Output High Voltage	V_{OH}			1.4	1.6	V
Output Low Voltage	V_{OL}		0.9	1.1		V
Offset Voltage	V_{OS}		1.125	1.2	1.375	V
Offset Magnitude Change	ΔV_{OS}		0	3	25	mV
Power-off Leakage	I_{OXD}	$V_{out} = V_{DD}$ or GND $V_{DD} = 0V$		± 1	± 10	μA
Output Short Circuit Current	I_{OSD}			-5.7	-8	mA

9. LVDS Switching Characteristics

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Differential Clock Rise Time	t_r	$R_L = 100 \Omega$ $C_L = 10 \text{ pF}$ (see figure)	0.2	0.7	1.0	ns
Differential Clock Fall Time	t_f		0.2	0.7	1.0	ns

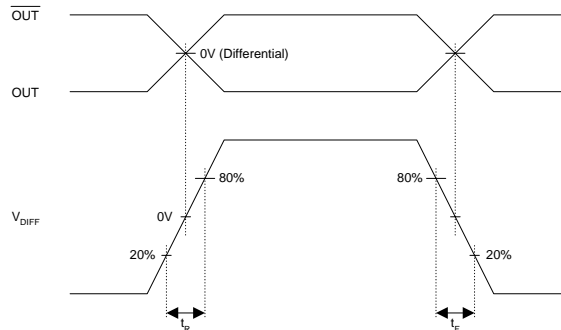
LVDS Levels Test Circuit



LVDS Switching Test Circuit



LVDS Transition Time Waveform



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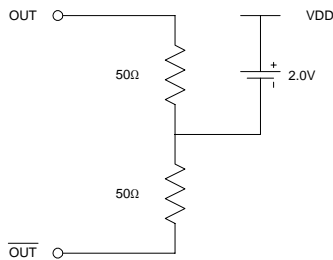
10. PECL Electrical Characteristics

PARAMETERS	SYMBOL	CONDITIONS	MIN.	MAX.	UNITS
Output High Voltage	V_{OH}	$R_L = 50 \text{ } \Omega$ to $(V_{DD} - 2V)$ (see figure)	$V_{DD} - 1.025$		V
Output Low Voltage	V_{OL}			$V_{DD} - 1.620$	V

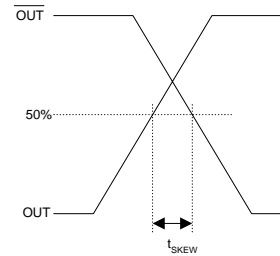
11. PECL Switching Characteristics

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Clock Rise Time	t_r	@20/80% - PECL		0.6	1.5	ns
Clock Fall Time	t_f	@80/20% - PECL		0.5	1.5	ns

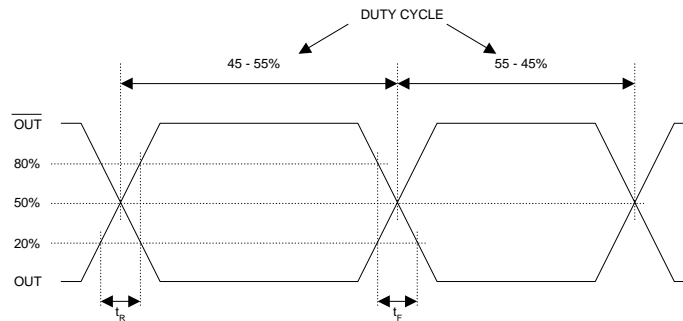
PECL Levels Test Circuit



PECL Output Skew

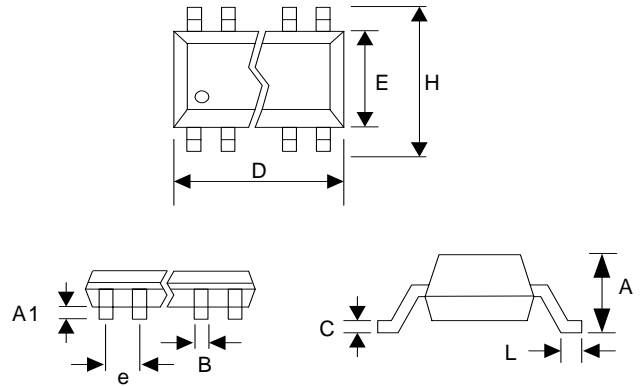


PECL Transition Time Waveform



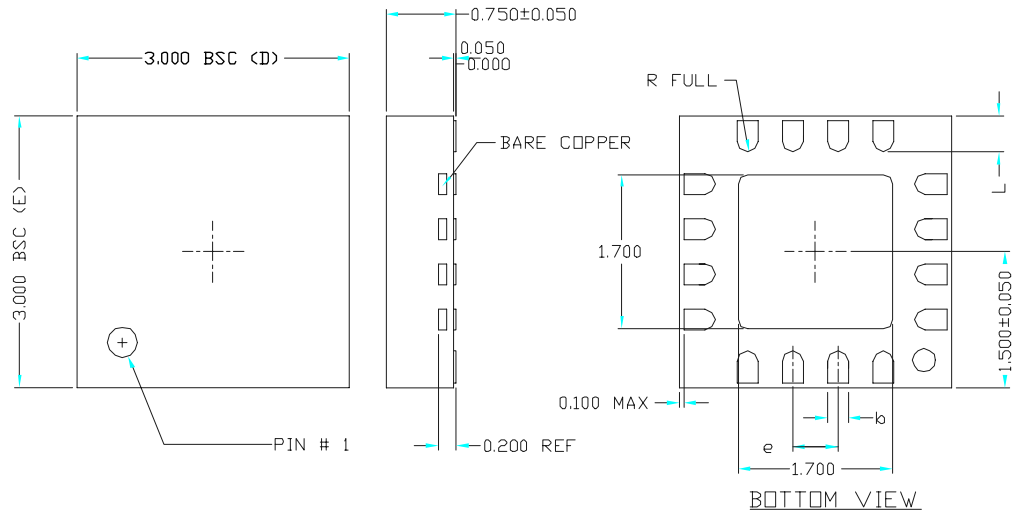
PACKAGE INFORMATION

16 PIN TSSOP (mm)		
Symbol	Min.	Max.
A	-	1.20
A1	0.05	0.15
B	0.19	0.30
C	0.09	0.20
D	4.90	5.10
E	4.30	4.50
H	6.40 BSC	
L	0.45	0.75
e	0.65 BSC	



VARIATIONS:

SYMBOL	16 LD		
	MIN	NOM	MAX
e	0.50 BSC		
b	0.18	0.23	0.30
L	0.30	0.40	0.50
ND	4		
NE	4		



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ORDERING INFORMATION

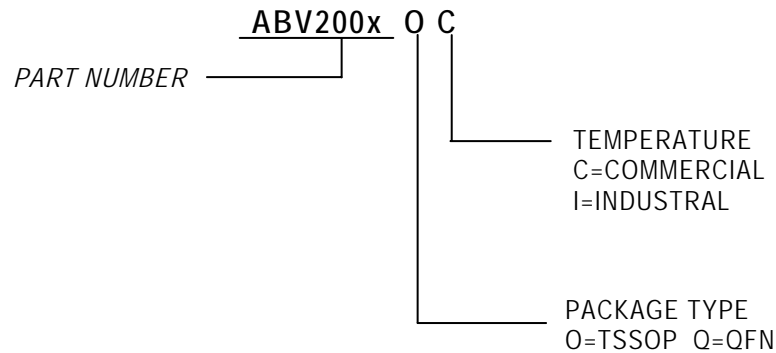
For part ordering, please contact our Sales Department:

30332 Esperanza., Rancho Santa Margarita, Ca 92688

Ph: 949-546-8000 Fax: 949-546-8001

PART NUMBER

The order number for this device is a combination of the following:
Device number, Package type and Operating temperature range



Order Number	Marking	Package Option
ABV2005OC	ABV2005OC	16-Pin TSSOP (Tube)
ABV2005OC-T	ABV2005OC	16-Pin TSSOP (Tape and Reel)
ABV2005QC	ABV2005QC	16-Pin 3x3 QFN (Tube)
ABV2005QC-T	ABV2005QC	16-Pin 3x3 QFN (Tape and Reel)
ABV2006QC	ABV2006QC	16-Pin 3x3 QFN (Tube)
ABV2006QC-T	ABV2006QC	16-Pin 3x3 QFN (Tape and Reel)
ABV2007OC	ABV2007OC	16-Pin TSSOP (Tube)
ABV2007OC-T	ABV2007OC	16-Pin TSSOP (Tape and Reel)
ABV2008OC	ABV2008OC	16-Pin TSSOP (Tube)
ABV2008OC-T	ABV2008OC	16-Pin TSSOP (Tape and Reel)
ABV2008QC	ABV2008QC	16-Pin 3x3 QFN (Tube)
ABV2008QC-T	ABV2008QC	16-Pin 3x3 QFN (Tape and Reel)
ABV2009OC	ABV2009OC	16-Pin TSSOP (Tube)
ABV2009OC-T	ABV2009OC	16-Pin TSSOP (Tape and Reel)
ABV2009QC	ABV2009QC	16-Pin 3x3 QFN (Tube)
ABV2009QC-T	ABV2009QC	16-Pin 3x3 QFN (Tape and Reel)

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